

APPLICATION # 10/783825

BRS	L1	44349	epitaxial adj layer	US-PGPUB; USPAT; EPO; JPO; DERWENT
BRS	L2	53654	1 adn hbt	US-PGPUB; USPAT; EPO; JPO; DERWENT
BRS	L3	233	1 with ((heterojunction adj bipolar adj transistor) or hbt)	US-PGPUB; USPAT; EPO; JPO; DERWENT
BRS	L4	1550	mos with 1	US-PGPUB; USPAT; EPO; JPO; DERWENT
BRS	L5	0	4 and (bipolar with (input adj control))	US-PGPUB; USPAT; EPO; JPO; DERWENT
BRS	L6	18	4 and (bipolar with impedance)	US-PGPUB; USPAT; EPO; JPO; DERWENT
BRS	L7	116116	330/\$.ccls. and (bipolar with (control adj input)) adn fet	US-PGPUB; USPAT; EPO; JPO; DERWENT
BRS	L8	12	330/\$.ccls. and (bipolar with (control adj input)) and fet	US-PGPUB; USPAT; EPO; JPO; DERWENT
BRS	L9	15	("20020024390" "3786364" "3792316" "3992678" "4074334" "4355341" "4673886" "5357089" "5371477" "5696467" "5917382" "6014059" "6081161" "6121841" "6137366").PN.	US-PGPUB; USPAT; USOCR
BRS	L10	7	("3845405" "4729129" "4859967" "5081425" "5357089" "5423081" "5493255").PN.	US-PGPUB; USPAT; USOCR